

Product data sheet

1. General description

Planar passivated ultra sensitive gate Silicon Controlled Rectifier in a SOT223 surface mountable plastic package.

2. Features and benefits

- Planar passivated for voltage ruggedness and reliability
- Ultra sensitive gate
- Surface mountable package

3. Applications

- Electronic ballasts
- Safety shut down and protection circuits
- Sensing circuits
- Smoke detectors
- Switched Mode Power Supplies

4. Quick reference data

Table 1. Quid	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	400	V
V _{RRM}	repetitive peak reverse voltage		-	-	400	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	8	A
Tj	junction temperature		-	-	125	°C
I _{T(RMS)}	RMS on-state current	half sine wave; T _{sp} ≤ 114 °C; <u>Fig. 1;</u> <u>Fig. 2</u>	-	-	0.8	A
Static characte	eristics		 			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 9</u>	-	3	12	μA





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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic charateristics							
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 268 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		-	150	-	V/µs

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	4	A-P+K
2	А	anode		G sym037
3	G	gate		
4	mb	mounting base; connected to anode	☐1	

6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
EC103D1W	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223

7. Marking

Table 4. Marking codes	
Type number	Marking code
EC103D1W	WYM-103D1W

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	400	V
V _{RRM}	repetitive peak reverse voltage		-	400	V
I _{T(AV)}	average on-state current	half sine wave; $T_{sp} \le 114 \text{ °C}$; Fig. 3	-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{sp} ≤ 114 °C; <u>Fig. 1;</u> <u>Fig. 2</u>	-	0.8	A

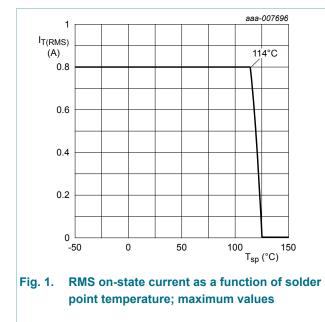
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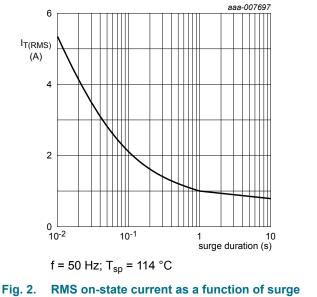
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Symbol	Parameter	Conditions	Min	Max	Unit
I _{TSM}	non-repetitive peak on-state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	-	9	A
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse	-	0.32	A ² s
dl _T /dt	rate of rise of on-state current	I_T = 2 A; I_G = 0.01 A; dI_G/dt = 0.1 A/µs	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

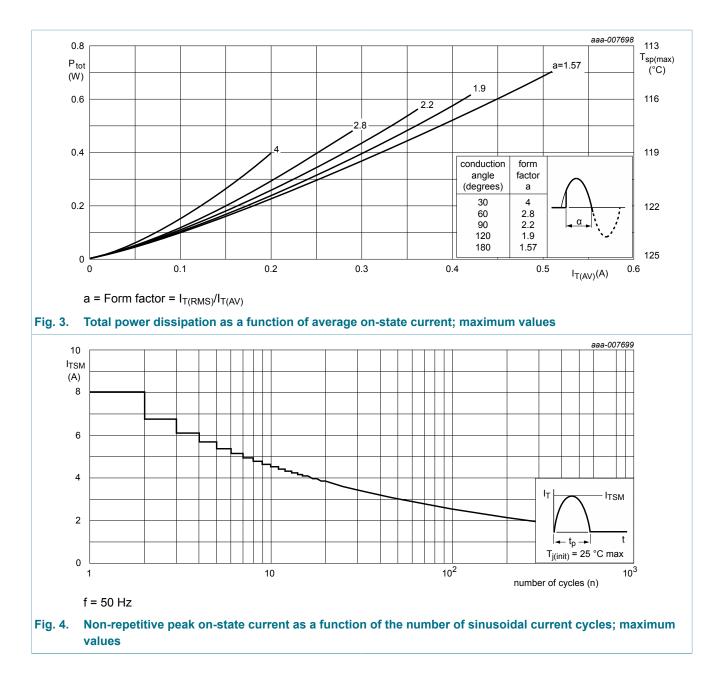




duration; maximum values

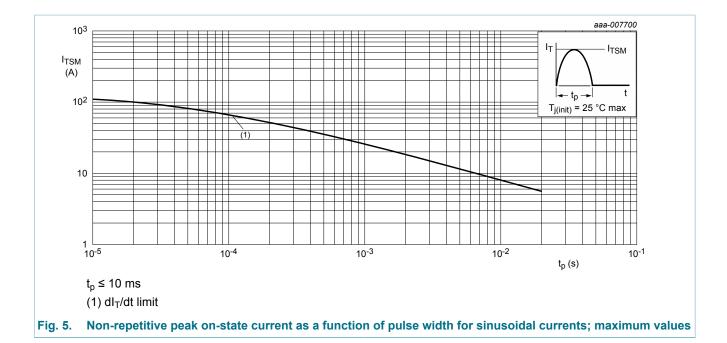
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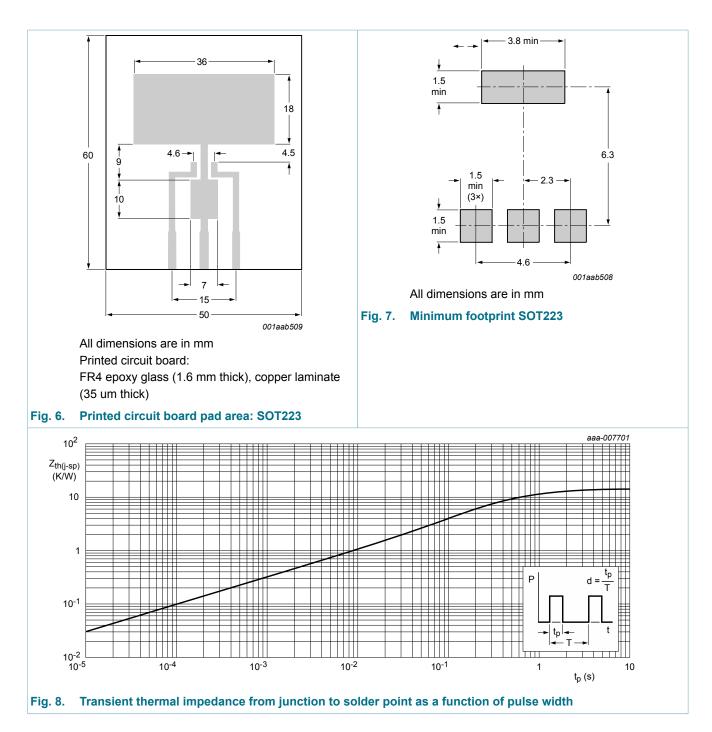
9. Thermal characteristics

Table 6.Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	<u>Fig. 8</u>	-	-	15	K/W
R _{th(j-a)}	thermal resistance from junction to	printed circuit board mounted; minimum pad area; in free air; Fig. 6	-	70	-	K/W
	ambient	printed circuit board mounted; minimum footprint; in free air; Fig. 7	-	156	-	K/W

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10. Characteristics

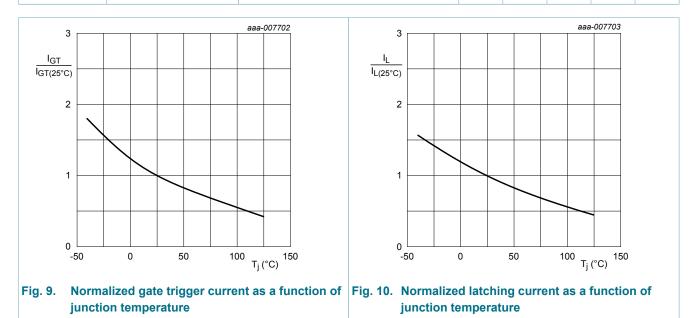
Table 7. Ch	aracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static charac	Static characteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 9</u>		-	3	12	μA

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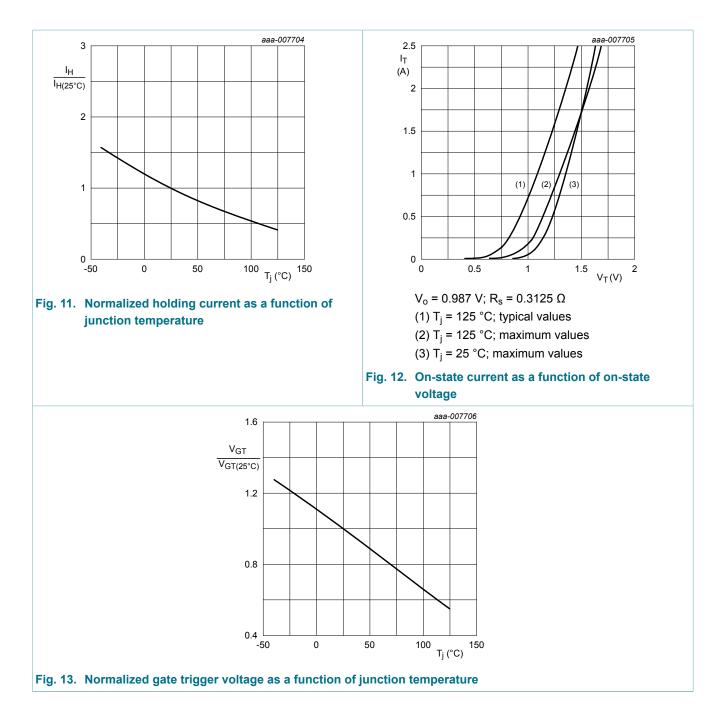
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
IL	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; Fig. 10		-	2	6	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>		-	2	5	mA
V _T	on-state voltage	I _T = 1 A; T _j = 25 °C; <u>Fig. 12</u>		-	1.2	1.35	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 13		-	0.5	0.8	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 13		0.2	0.3	-	V
I _D	off-state current	V _D = 400 V; T _j = 125 °C		-	0.05	0.1	mA
I _R	reverse current	V _R = 400 V; T _j = 125 °C		-	0.05	0.1	mA
Dynamic cl	harateristics	1	1	1		1	
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 268 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate		-	150	-	V/µs

open circuit



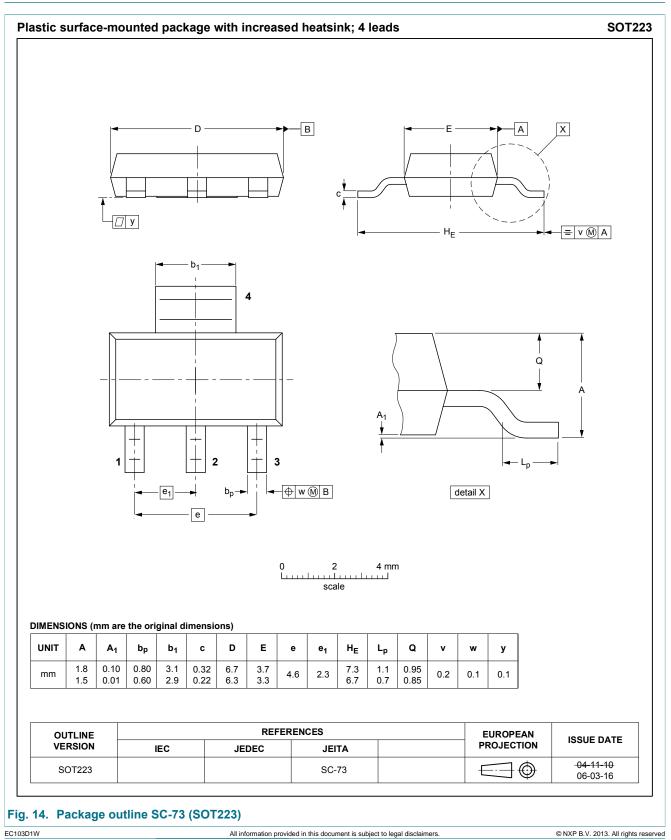
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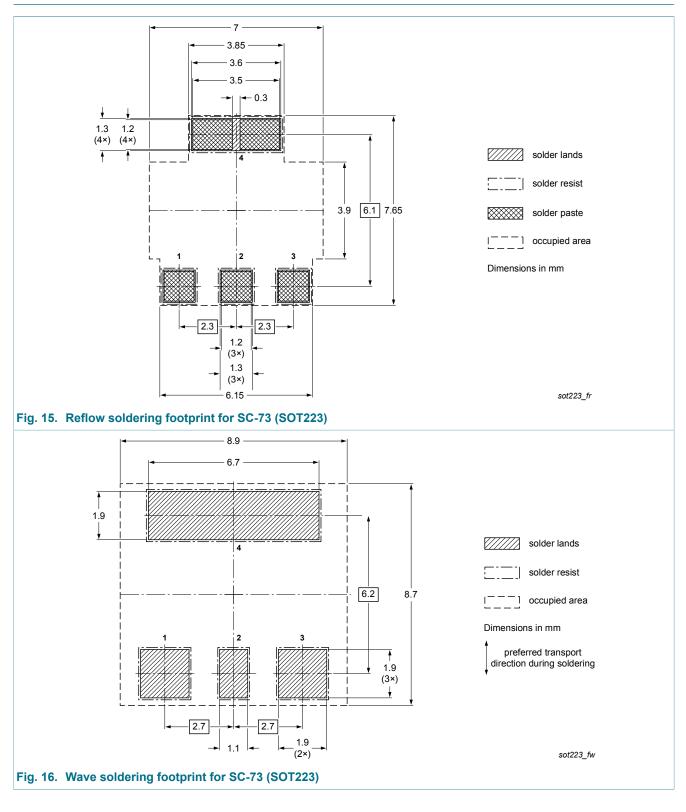
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11. Package outline



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12. Soldering



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13. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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14. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	
8	Limiting values	2
9	Thermal characteristics	5
10	Characteristics	6
11	Package outline	9
12	Soldering	10
13	Legal information	
13 13.1	Legal information Data sheet status	11 11
	Legal information Data sheet status Definitions	11 11 11
13.1	Legal information Data sheet status	11 11 11

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